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# **ON Semiconductor**®

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- Max  $r_{DS(on)} = 6 \text{ m}\Omega$  at  $V_{GS} = 10 \text{ V}$ ,  $I_D = 14 \text{ A}$
- Max  $r_{DS(on)} = 11 \text{ m}\Omega$  at  $V_{GS} = 6 \text{ V}$ ,  $I_D = 11.5 \text{ A}$
- Advanced Package and Silicon combination for low r<sub>DS(on)</sub> and high efficiency
- MSL1 robust package design
- 100% UIL tested
- RoHS Compliant

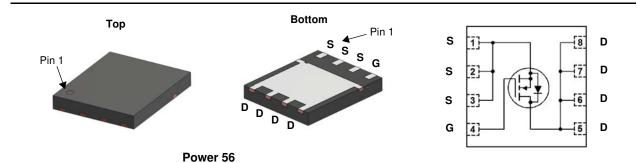


## **General Description**

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench<sup>®</sup> process thant has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

### **Applications**

- Primary DC-DC MOSFET
- Secondary Synchronous Rectifier
- Load Switch



MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units V
V <sub>DS</sub>	Drain to Source Voltage	Drain to Source Voltage			
V <sub>GS</sub>	Gate to Source Voltage			±20	V
	Drain Current -Continuous	T <sub>C</sub> = 25 °C		45	
ID	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	14	Α
	-Pulsed			260	
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	541	mJ
P <sub>D</sub>	Power Dissipation $T_{\rm C} = 25 ^{\circ}{\rm C}$			125	14/
	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	2.7	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C

#### **Thermal Characteristics**

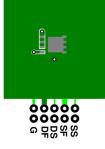
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.0	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note	e 1a) 45	C/ W

#### Package Marking and Ordering Information

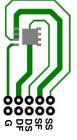
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86152	FDMS86152	Power 56	13 "	12 mm	3000 units

March 2015

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics					1	
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	100			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		90		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80 V, V <sub>GS</sub> = 0 V			1	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	2	3	4	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_{.l}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-10		mV/°C	
0		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 14 A		5.2	6		
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = 6 \text{ V}, \text{ I}_{D} = 11.5 \text{ A}$		7.3	11	mΩ	
- ( - )		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 14 A, T <sub>J</sub> = 125 °C		8.7	10		
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 14 A		42		S	
C <sub>iss</sub> C <sub>oss</sub> C <sub>rss</sub>	Input Capacitance Output Capacitance Reverse Transfer Capacitance	$V_{DS} = 50 V, V_{GS} = 0 V,$ f = 1 MHz		2530 595 22	3370 795 35	pF pF pF	
R <sub>g</sub>	Gate Resistance			0.9		Ω	
Switching	g Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time			17	30	ns	
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 50 V, I <sub>D</sub> = 14 A,		6	12	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		25	39	ns	
t <sub>f</sub>	Fall Time			5	10	ns	
Qg	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		36	50	nC	
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 6 V$ $V_{DD} = 50 V,$		23	33	nC	
Q <sub>gs</sub>	Gate to Source Charge	I <sub>D</sub> = 14 A		10.7		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			7.2		nC	
Drain-Soເ	urce Diode Characteristics						
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.1 A$ (Note 2)		0.70	1.2	v	
		$V_{GS} = 0 V, I_S = 14 A$ (Note 2)		0.78	1.3		
t <sub>rr</sub>	Reverse Recovery Time	— I <sub>F</sub> = 14 A, di/dt = 100 A/μs		59	94	ns	
Q <sub>rr</sub>	Reverse Recovery Charge	$F = 1 + 70, 0000 = 100 70 \mu 3$		74	119	nC	



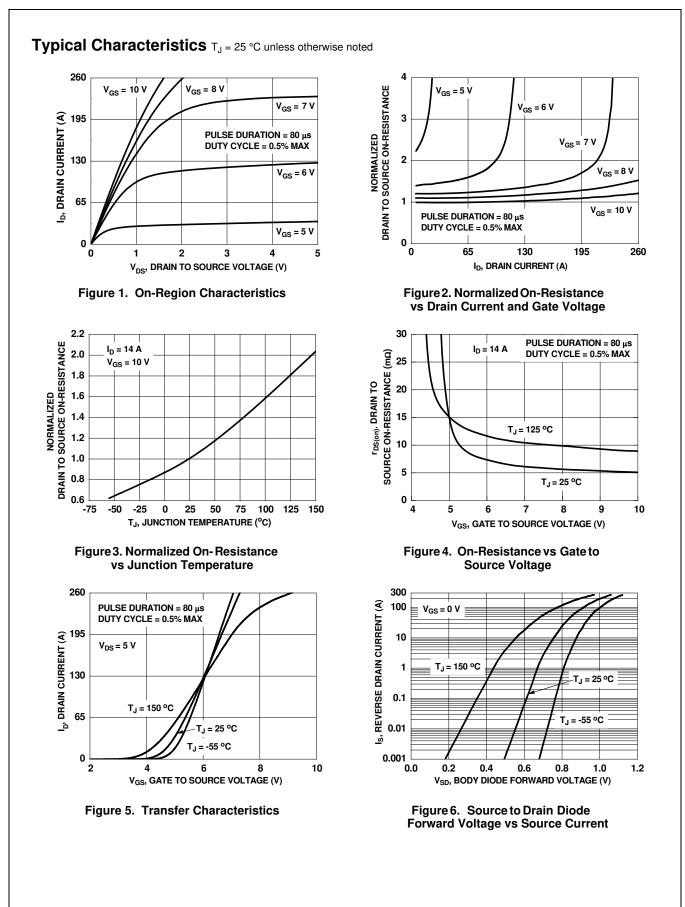
a. 45 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



b. 115 °C/W when mounted on a minimum pad of 2 oz copper.

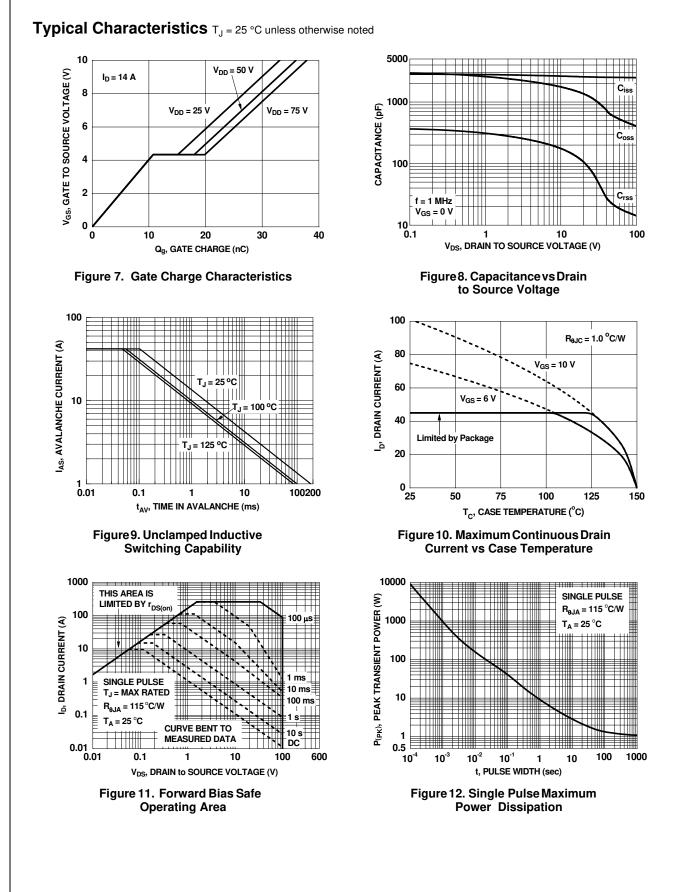
2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0%.

3. Starting  $T_J$  = 25 °C, L = 3 mH,  $I_{AS}$  = 19 A,  $V_{DD}$  = 100 V,  $V_{GS}$  = 10 V. 100% test at L = 0.3 mH,  $I_{AS}$  = 42 A.

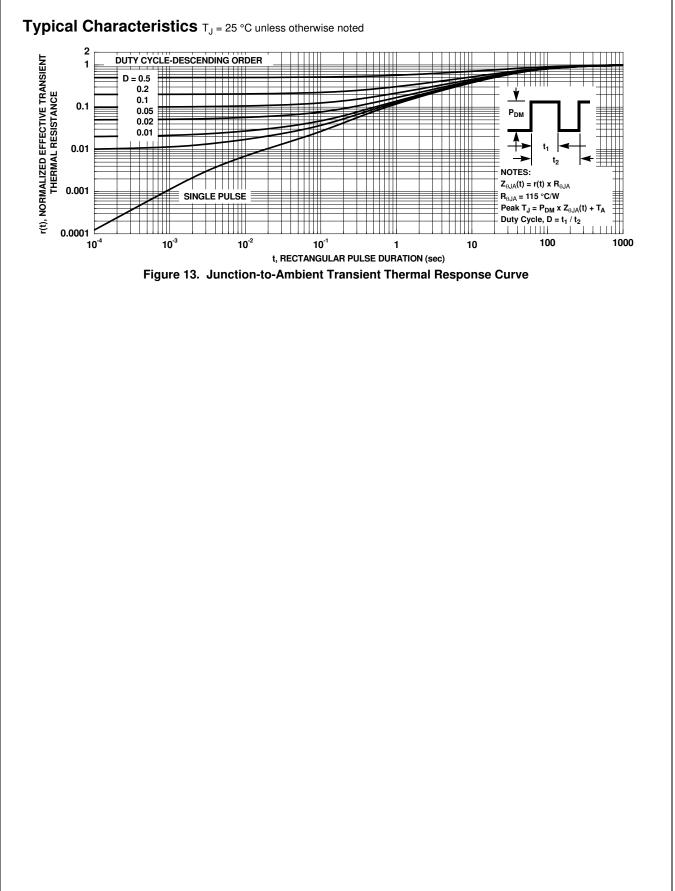


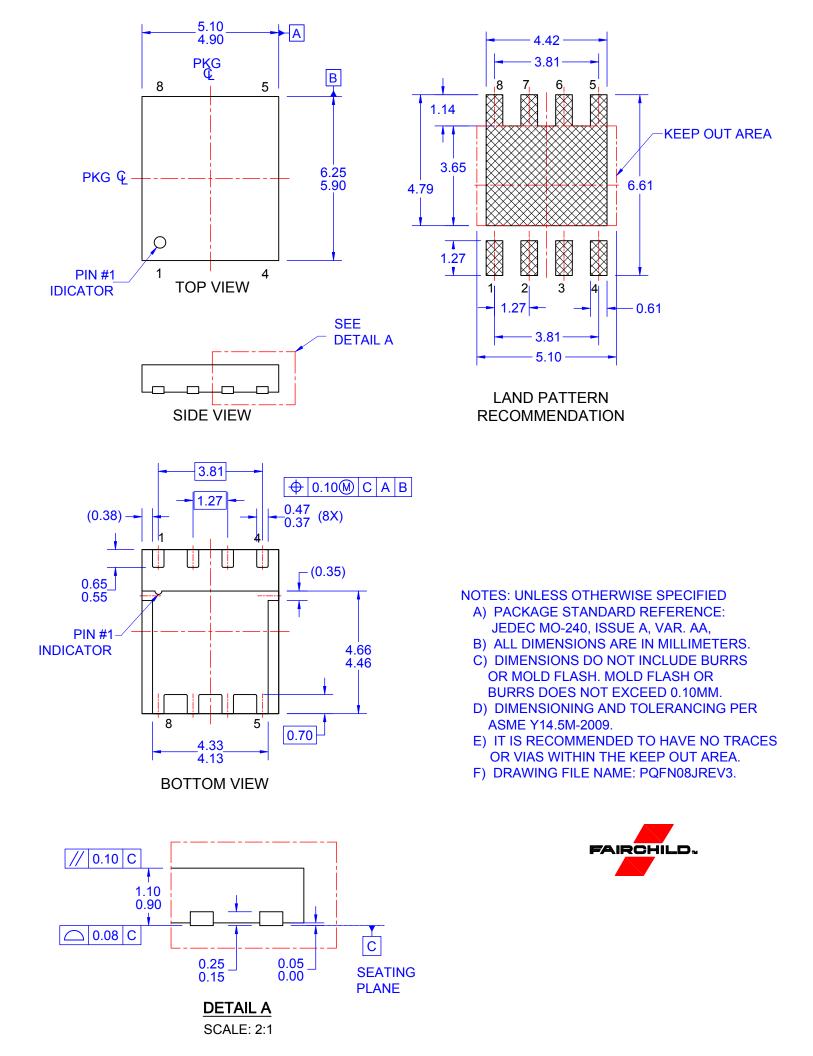
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